

# PH100-SIUV-OD1-D0

Photodiode detector for laser power measurement up to 38 mW.



#### PRODUCT FAMILY KEY FEATURES

#### LARGE APERTURES

10 mm Ø for the silicon sensors

#### **3 VERSIONS**

- Silicon 350 1080 nm, up to 750 mW
- Silicon-UV 210 1080 nm, up to 38 mW
- Germanium 800 1650 nm, up to 500 mW

#### **CHOICE OF ATTENUATORS**

- OD0.3: 50% transmission (for PH100-SI<sup>UV</sup> only)
- OD1: 10% transmission
- OD2: 1% transmission

#### **HIGH ACCURACY**

The new PH100-SI-HA presents the lowest calibration uncertainty to date.

13.7 mm

#### PRECISE CALIBRATION

Wavelength selection in 1 nm steps

#### SMART INTERFACE

Containing all the calibration data

#### **COMPATIBLE STAND**

STAND-D-233

## **SPECIFICATIONS**

### **MEASUREMENT CAPABILITIES**

Maximum average power <sup>1</sup>	38 mW
Noise equivalent power <sup>2</sup>	200 pW
Spectral range	400 - 1080 nm
Typical rise time	0.2 s
Power calibration uncertainty <sup>3</sup>	±5.0 % (400 - 1009 nm) ±7.5 % (1010 - 1080 nm)
Peak sensitivity	850 nm
Minimum repetition rate <sup>4</sup>	155 kHz
1. At 532 nm, with attenuator. See curves for maximum power at other wavelengths.	

- 2. At 850 nm. Nominal value. Actual value depends on environmental electromagnetic interference and wavelength.
- 3. With attenuator. See user manual for calibration uncertainty without attenuator.
- 4. See user manual for details.

## DAMAGE THRESHOLDS

100 W/cm<sup>2</sup> Maximum average power density

## PHYSICAL CHARACTERISTICS

Aperture diameter	10 mm
Absorber	SiUV
Dimensions	38.1Ø x 36D mm

Dimensions 0.14 kg Weight

ORDERING INFORMATION

Distance to sensor face

PH100-SiUV-OD1-D0 200881 PH100-SiUV-OD1-IDR-D0 203234

PH100-SiUV-OD1-INT-D0 202790

 $Specifications\ are\ subject\ to\ change\ without\ notice.\ Refer\ to\ the\ user\ manual\ for\ complete\ specifications.$ 

# **INTERESTED IN THIS PRODUCT?**



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